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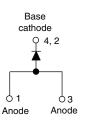
RoHS

COMPLIANT

High Performance Schottky Rectifier, 3.5 A



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D-PAK	(TO-252AA	
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PRODUCT SUMMARY								
Package	D-PAK (TO-252AA)							
I _{F(AV)}	3.5 A							
V _R	30 V							
V _F at I _F	See Electrical table							
I _{RM}	50 mA at 125 °C							
T _J max.	150 °C							
Diode variation	Single die							
E _{AS}	8 mJ							

FEATURES

- Popular D-PAK outline
- · Small foot print, surface mountable
- Low forward voltage drop
- · High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- · Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-30WQ03FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	3.5	A							
V _{RRM}		30	V							
I _{FSM}	t _p = 5 μs sine	535	A							
V _F	3 A _{pk} , T _J = 125 °C	0.35	V							
TJ	Range	-40 to +150	C°							

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-30WQ03FNPbF	UNITS					
Maximum DC reverse voltage	V _R	30	V					
Maximum working peak reverse voltage	V _{RWM}	30	v					

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS					
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 134 °C	3.5							
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	535	Α					
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	90						
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \ ^{\circ}C, \ I_{AS} = 2 \ A, \ L = 4 \ mH$	8	mJ						
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maximum	1.0	А						

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
		3 A	T ₁ = 25 °C	0.45	V				
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	6 A	1j=25 0	0.52					
	VFM \''	3 A	T ₁ = 125 °C	0.35					
		6 A	1j = 125 C	0.46					
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C		2	mA				
See fig. 2		T _J = 125 °C	$V_R = Rated V_R$	50					
Threshold voltage	V _{F(TO)}		·	0.22	V				
Forward slope resistance	r _t	r_t $T_J = T_J$ maximum		32.86	mΩ				
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	290	pF					
Typical series inductance	L _S	Measured lead to lead 5 mm	5.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R						

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER SYMBOL TEST CONDITIONS VALUES UNITS										
Maximum junction and storage temperature range	T_{J} ⁽¹⁾ , T_{Stg}		-40 to +150	°C						
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	4.7	°C/W						
Approvimeto weight			0.3	g						
Approximate weight			0.01	oz.						
Marking device		Case style D-PAK (similar to TO-252AA)	30WC	03FN						

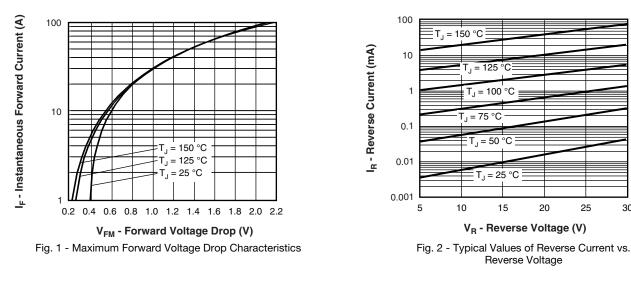
Note

(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink

VS-30WQ03FNPbF

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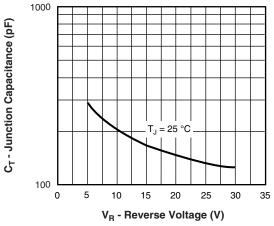


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

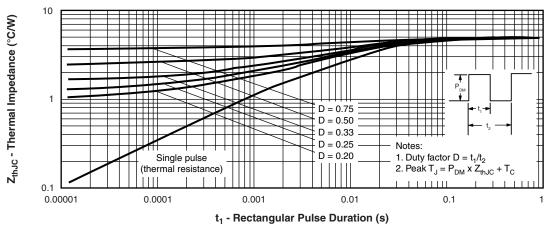
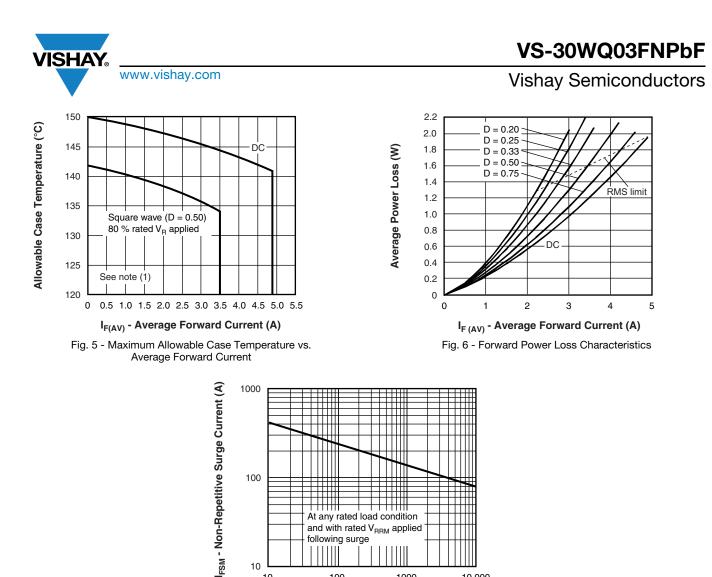


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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following surge

100

At any rated load condition and with rated V_{RRM} applied

t_p - Square Wave Pulse Duration (μs) Fig. 7 - Maximum Non-Repetitive Surge Current

1000

10 000

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = 80 \%$ rated V_R

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ORDERING INFORMATION TABLE

Device code	vs-	30	w	Q	03	FN	TRL	PbF		
	1	2	3	4	5	6	(7)	8		
	 Vishay Semiconductors product 									
	2 -	Cur	rent rati	ng (3.5 /	4)					
	3 -	Pac	kage ide	entifier:						
		VV =	D-PAK							
	4 -	Sch	ottky "Q	" series						
	5 -	Volt	tage rati	ng (03 =	: 30 V)					
	6 -	FN	= TO-25	52AA (D	-PAK)					
	7 -	• No	one = tu	be (50 p	ieces)					
		• TF	R = tape	and ree	el					
	 TRL = tape and reel (left oriented) 									
	 TRR = tape and reel (right oriented) 									
	8 -	PbF	= lead	(Pb)-fre	e					

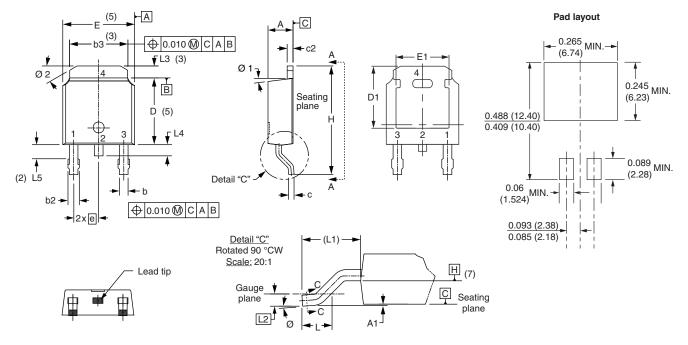
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95016						
Part marking information	www.vishay.com/doc?95059						
Packaging information	www.vishay.com/doc?95033						





D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension uncontrolled in L5

⁽³⁾ Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁶⁾ Dimension b1 and c1 applied to base metal only

⁽⁷⁾ Datum A and B to be determined at datum plane H

⁽⁸⁾ Outline conforms to JEDEC outline TO-252AA

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